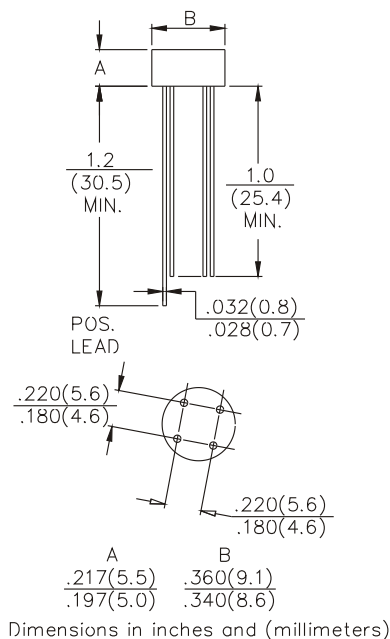


SINGLE-PHASE SILICON BRIDGE



- High reverse voltage to 1000V
- Surge overload ratings to 50 amperes peak
- Good for printed circuit board assembly
- Mounting position: Any
- Weight: 1.20 grams

VOLTAGE RANGE
50 TO 1000 VOLTS
CURRENT
1.5 Amperes



Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

MAXIMUM RATINGS (At T_A=25°C unless otherwise noted)

RATINGS	SYMBOLS	W005M	W01M	W02M	W04M	W06M	W08M	W010M	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Bridge Input Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current at @ $T_A=25^{\circ}C$	I_O	1.5							A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	50							A
Operating Temperature Range	T_J	-55 to +125							$^{\circ}C$
Storage Temperature Range	T_{STG}	-55 to +150							$^{\circ}C$

ELECTRICAL CHARACTERISTICS (At T_A=25°C unless otherwise noted)

CHARACTERISTICS			W005M	W01M	W02M	W04M	W06M	W08M	W010M	UNITS
Maximum Forward Voltage drop per element of 1.0A DC		V _F	1.0							V
Maximum Reverse Current at Rated DC Blocking Voltage per element	@ T _A =25°C	I _R	10							μ A
	@ T _A =100°C		1							mA

W005M thru W10M

SINGLE-PHASE SILICON BRIDGE



CHENG-YI ELECTRONIC

RATING AND CHARACTERISTICS CURVES W005M THRU W10M

Fig.1 - MAXIMUM NON-REPETITIVE
FORWARD SURGE CURRENT

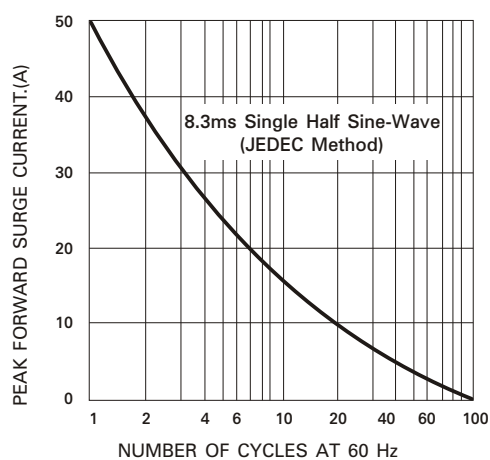


Fig.2 - TYPICAL FORWARD CURRENT
DERATING CURVE

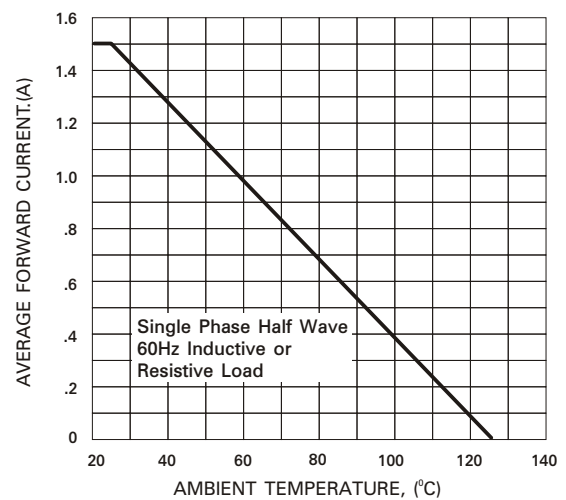


Fig.3 - TYPICAL INSTANTANEOUS FORWARD
CHARACTERISTICS

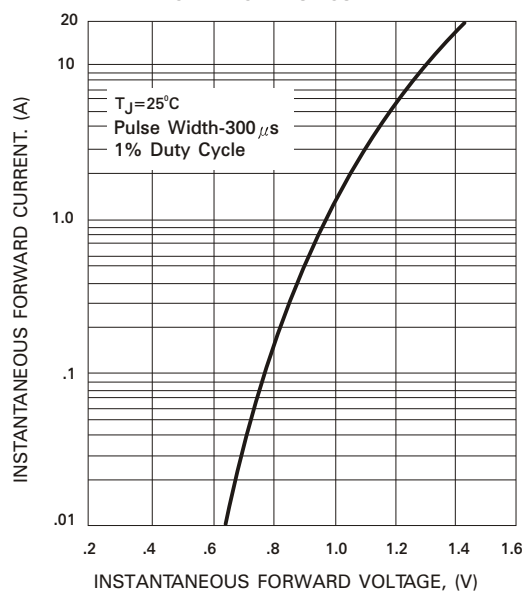


Fig.4 - TYPICAL REVERSE CHARACTERISTICS

